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# SFT1341

## Power MOSFET -40V, 112mΩ, -10A, Single P-Channel

### Features

- Low On-Resistance
- Low Gate Charge
- ESD Diode-Protected Gate
- High Speed Switching
- Low Gate Drive Voltage
- Pb-free and RoHS Compliance

### Specifications

**Absolute Maximum Ratings** at  $T_a = 25^\circ\text{C}$

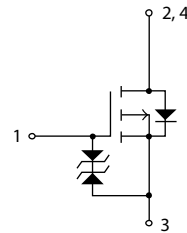
Parameter	Symbol	Value	Unit
Drain to Source Voltage	$V_{DSS}$	-40	V
Gate to Source Voltage	$V_{GSS}$	$\pm 10$	V
Drain Current (DC)	$I_D$	-10	A
Drain Current $PW \leq 10\mu\text{s}$ , duty cycle $\leq 1\%$	$I_{DP}$	-40	A
Power Dissipation	$P_D$	1.0	W
		$T_c = 25^\circ\text{C}$	15
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

### Thermal Resistance Ratings

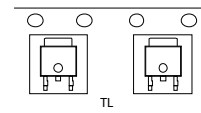
Parameter	Symbol	Value	Unit
Junction to Case Steady State	$R_{\theta JC}$	8.33	$^\circ\text{C/W}$
Junction to Ambient *1	$R_{\theta JA}$	125	

Note : \*1 Insertion mounted

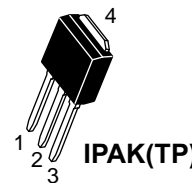
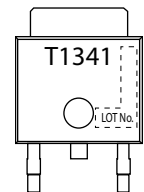
### Electrical Connection P-Channel



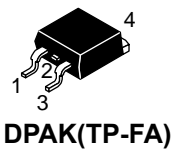
### Packing Type: TL



### Marking



**IPAK (TP)**



**DPAK (TP-FA)**

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

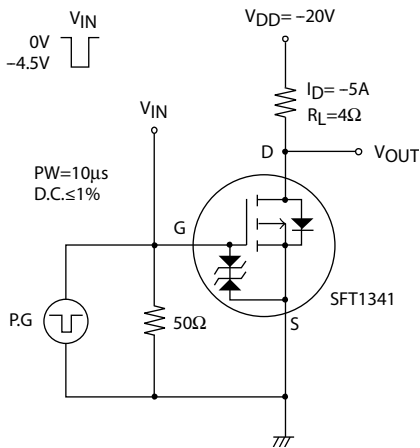
# SFT1341

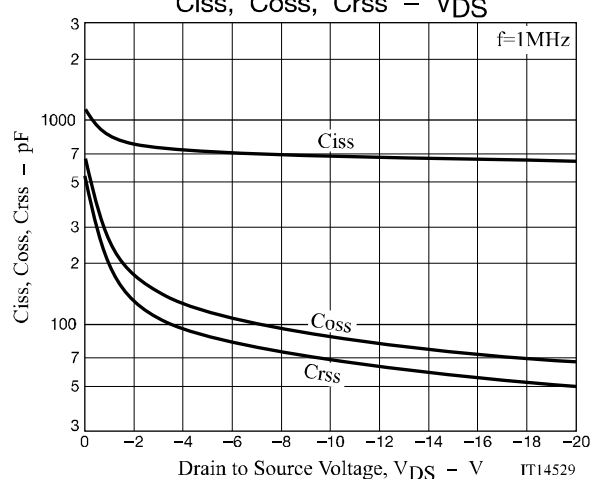
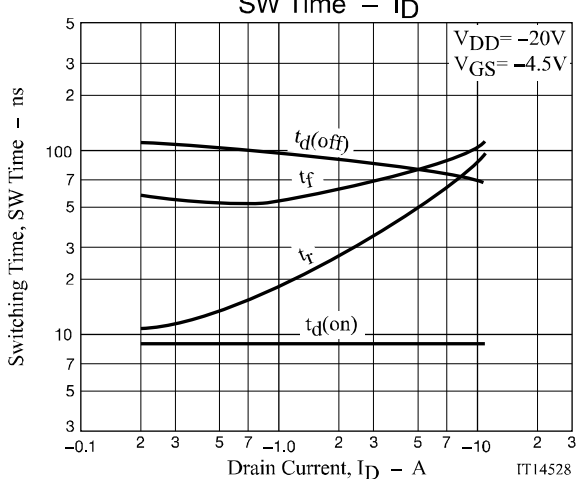
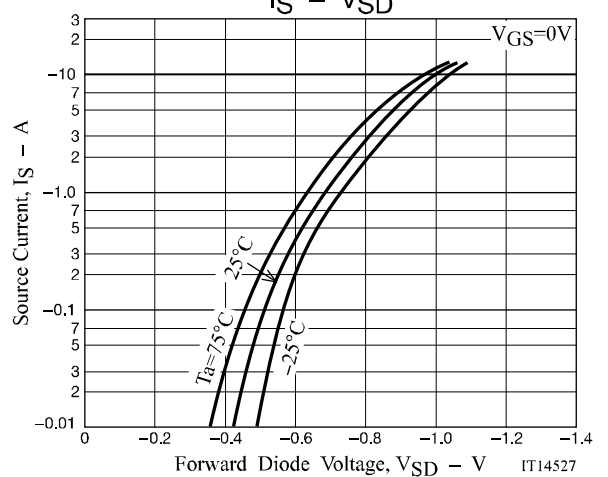
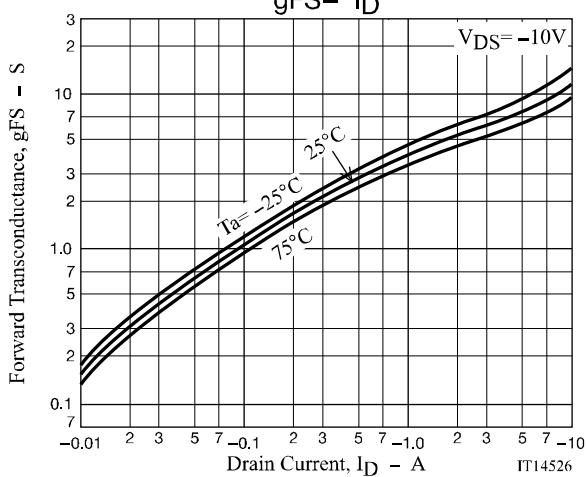
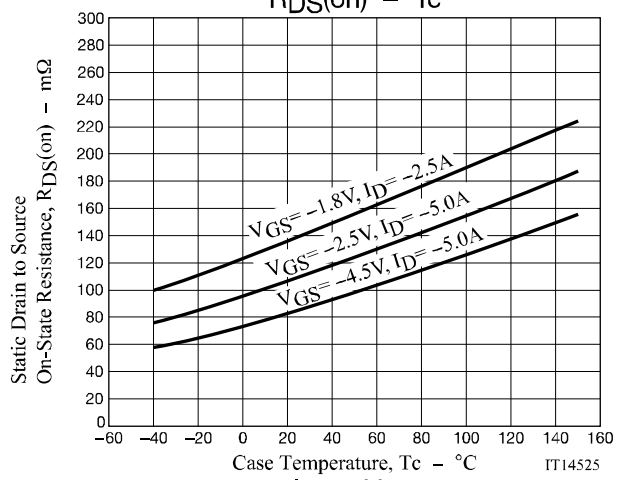
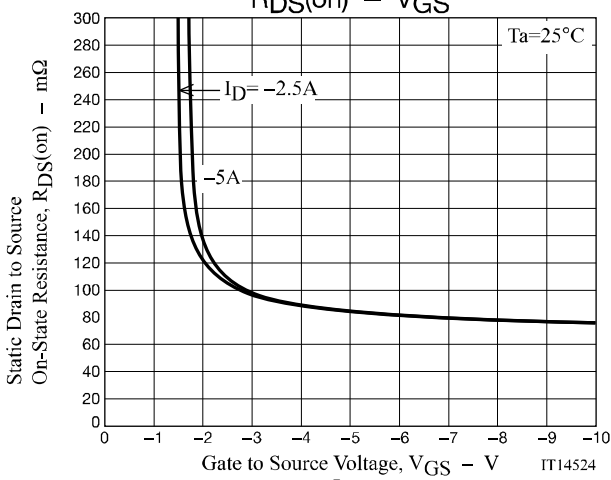
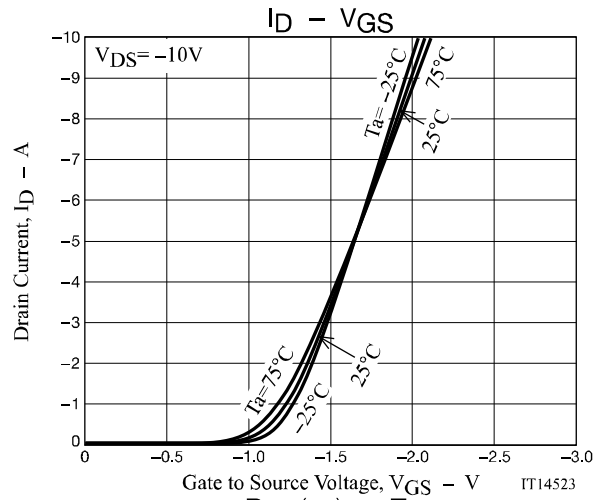
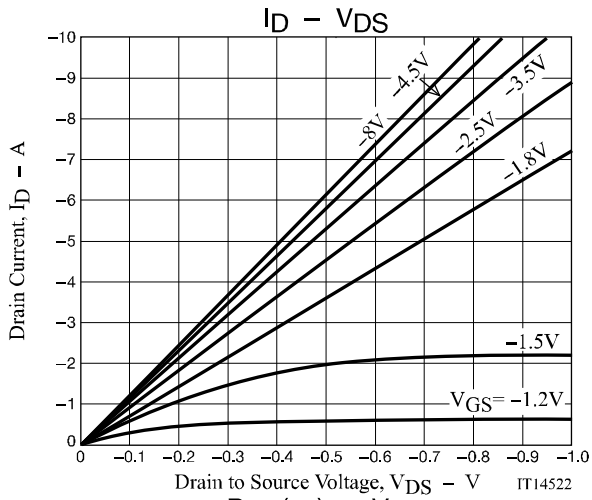
## Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = -1\text{mA}$ , $V_{GS} = 0\text{V}$	-40			V
Zero-Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -40\text{V}$ , $V_{GS} = 0\text{V}$			-1	$\mu\text{A}$
Gate to Source Leakage Current	$I_{GSS}$	$V_{GS} = \pm 8\text{V}$ , $V_{DS} = 0\text{V}$			$\pm 10$	$\mu\text{A}$
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = -10\text{V}$ , $I_D = -1\text{mA}$	-0.4		-1.4	V
Forward Transconductance	$g_{FS}$	$V_{DS} = -10\text{V}$ , $I_D = -5\text{A}$	4.6	7.7		S
Static Drain to Source On-State Resistance	$R_{DS(on)1}$	$I_D = -5\text{A}$ , $V_{GS} = -4.5\text{V}$		86	112	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D = -5\text{A}$ , $V_{GS} = -2.5\text{V}$		110	154	$\text{m}\Omega$
	$R_{DS(on)3}$	$I_D = -2.5\text{A}$ , $V_{GS} = -1.8\text{V}$		140	210	$\text{m}\Omega$
Input Capacitance	$C_{iss}$	$V_{DS} = -20\text{V}$ , $f = 1\text{MHz}$		650		$\text{pF}$
Output Capacitance	$C_{oss}$			65		$\text{pF}$
Reverse Transfer Capacitance	$C_{rss}$			50		$\text{pF}$
Turn-ON Delay Time	$t_{d(on)}$			9.0		ns
Rise Time	$t_r$	See specified Test Circuit.		50		ns
Turn-OFF Delay Time	$t_{d(off)}$			81		ns
Fall Time	$t_f$			80		ns
Total Gate Charge	$Q_g$			8.0		nC
Gate to Source Charge	$Q_{gs}$	$V_{DS} = -20\text{V}$ , $V_{GS} = -4.5\text{V}$ , $I_D = -10\text{A}$		1.4		nC
Gate to Drain "Miller" Charge	$Q_{gd}$			2.5		nC
Forward Diode Voltage	$V_{SD}$		$I_S = -10\text{A}$ , $V_{GS} = 0\text{V}$		-1.0	-1.5

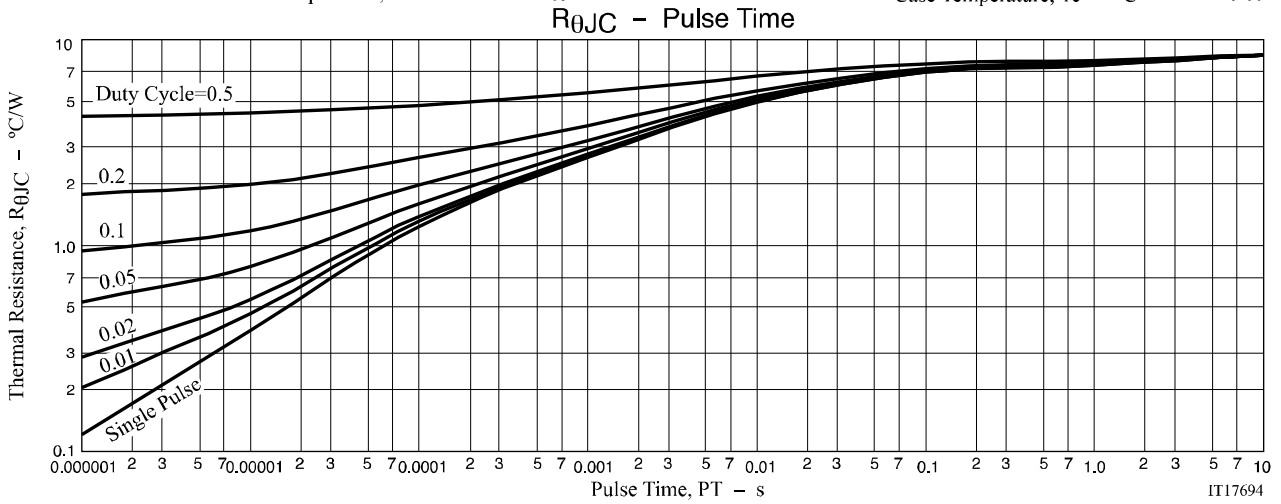
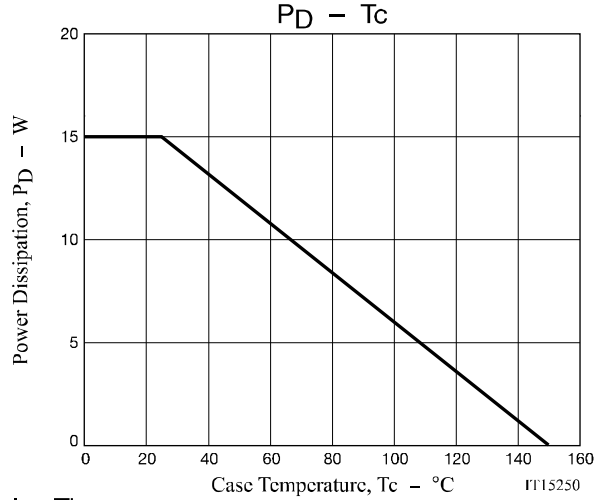
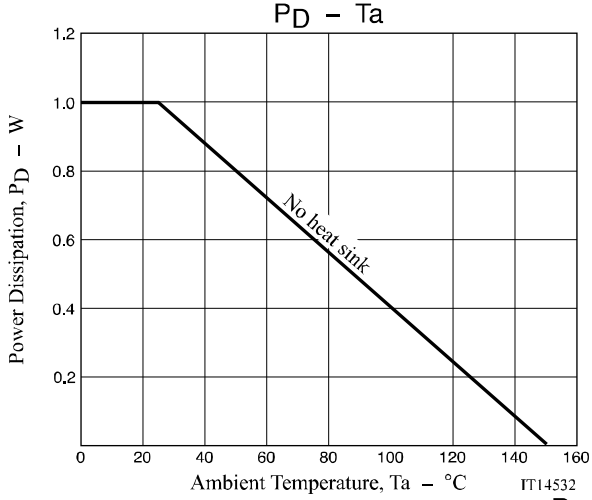
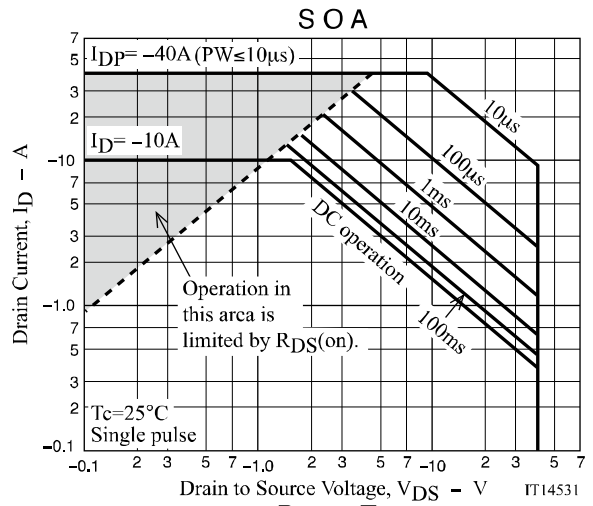
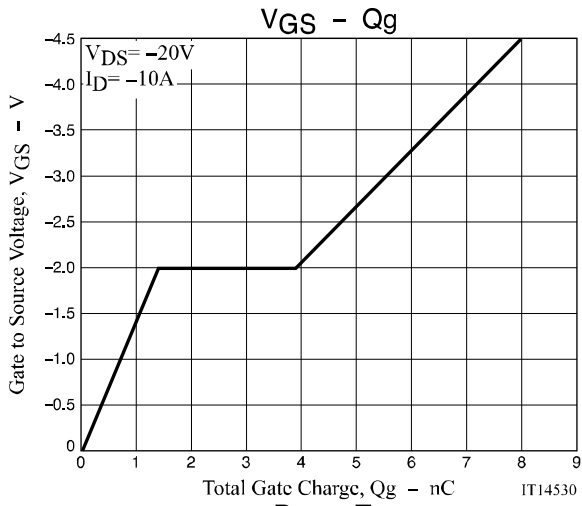
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## Switching Time Test Circuit





# SFT1341



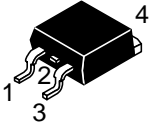
# SFT1341

## Package Dimensions

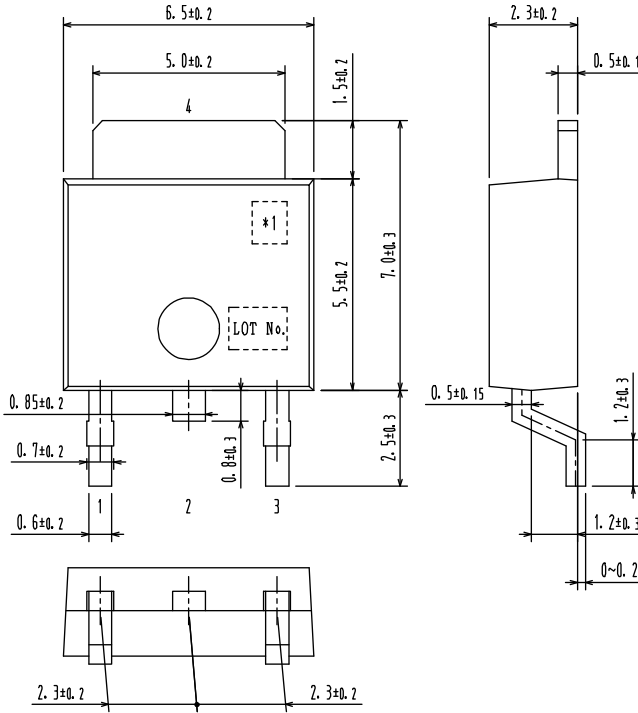
SFT1341-TL-E/SFT1341-TL-W

## DPAK/TP-FA

unit : mm



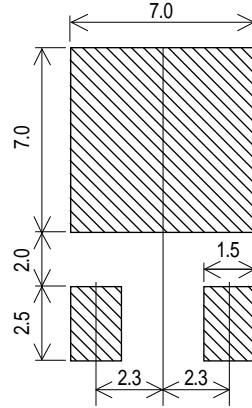
- 1:Gate
- 2:Drain
- 3:Source
- 4:Drain



Pin 2 is idle pin with electrical designation only carried.

\*1:Lot indication

## Recommended Soldering Footprint



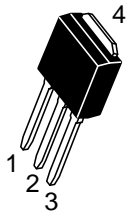
# SFT1341

## Package Dimensions

SFT1341-E/ SFT1341-W

### IPAK/TP

Unit : mm

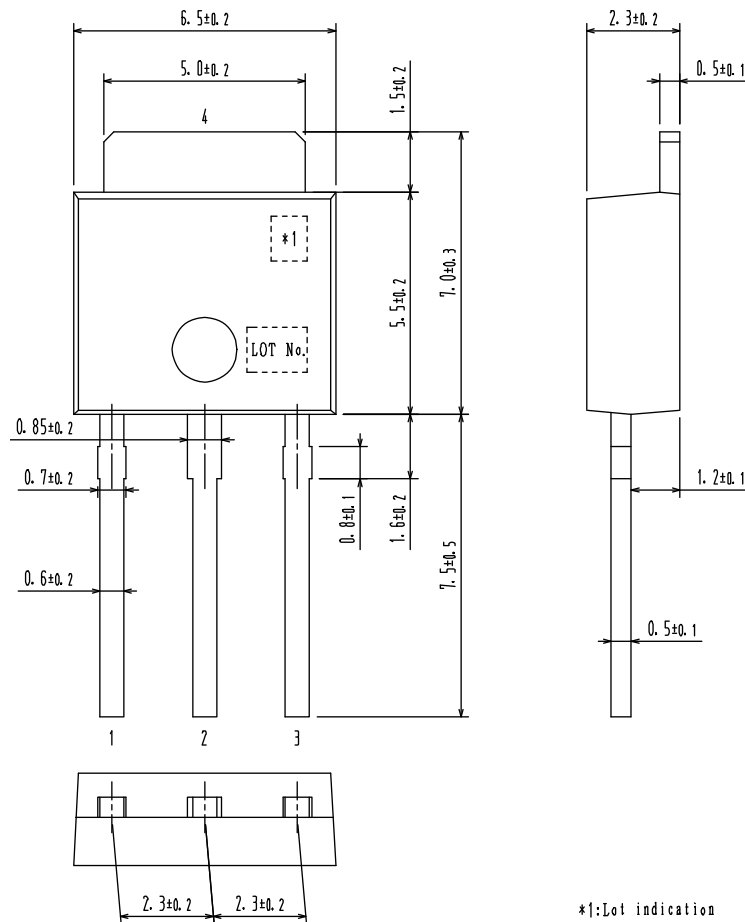


1:Gate

2:Drain

3:Source

4:Drain



\*1: Lot indication

### Ordering & Package Information

Device	Package	Shipping	Note
SFT1341-E	IPAK(TP)	500pcs. / bag	Pb-Free
SFT1341-W	SC-64 TO-251		Pb-Free and Halogen Free
SFT1341-TL-E	DPAK(TP-FA)	700pcs. / reel	Pb-Free
SFT1341-TL-W	SC-63 TO-252		Pb-Free and Halogen Free

Note on usage : Since the SFT1341 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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